

# CMPA0560008S

0.5 – 6 GHz, 10 W GaN HPA

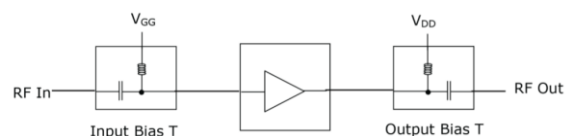
## Description

Wolfspeed’s CMPA0560008S is a 10W packaged MMIC HPA utilizing Wolfspeed’s high performance, 0.15um GaN on SiC production process. The CMPA0560008S operates from 0.5-6 GHz and supports a variety of RF applications such as electronic warfare, test and measurement, radar among others. The CMPA0560008S achieves 10 W of saturated output power with 12 dB of large signal gain and typically 40% power-added efficiency under CW operation.

Packaged in a 5x5 mm plastic overmold QFN, the CMPA0560008S provides superior performance and environmental robustness in a small form factor allowing customers to improve SWaP-C benchmarks in their next-generation systems.



**Figure 1. CMPA0560008S**



**Figure 2. Functional Block Diagram**

## Features

- Psat: 10 W
- PAE: 40 %
- LSG: 12 dB
- S21: 19 dB
- S11: -11 dB
- S22: -8 dB
- CW operation
- Small 5 x 5 mm footprint

Note: Features are typical performance across frequency under 25C operation. Please reference performance charts for additional information.

## Applications

- Electronic Warfare
- Test and Measurement
- Radar
- General Amplification

**RoHS**  
COMPLIANT

### Absolute Maximum Ratings

Parameter	Symbol	Units	Value	Conditions
Drain Voltage	$V_d$	V	28	
Gate Voltage	$V_g$	V	-10, +2	
Drain Current	$I_d$	A	1.3	
Gate Current	$I_g$	mA	3.8	
Input Power	$P_{in}$	dBm	29	
Dissipated Power	$P_{diss}$	W	25	85°C
Storage Temperature	$T_{stg}$	°C	-55, +150	
Mounting Temperature	$T_J$	°C	260	30 seconds
Junction Temperature	$T_J$	°C	225	
Output Mismatch Stress	VSWR	$\Psi$	5:1	

### Recommended Operating Conditions

Parameter	Symbol	Units	Typical Value	Conditions
Drain Voltage	Vd	V	28	
Gate Voltage	Vg	V	-2.0	
Drain Current	Idq	mA	220	
Input Power	Pin	dBm	28	
Case Temperature	Tcase	°C	-40 to 85	

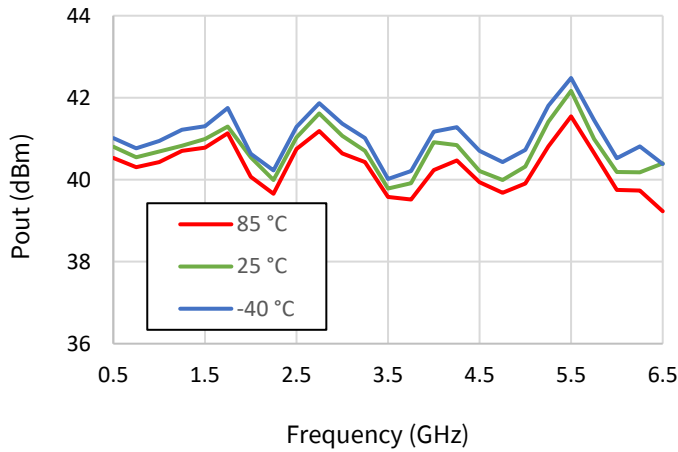
### RF Specifications

Test conditions unless otherwise noted:  $V_d=28V$ ,  $I_{dq}=220mA$ , CW,  $T_{base}=25^\circ C$

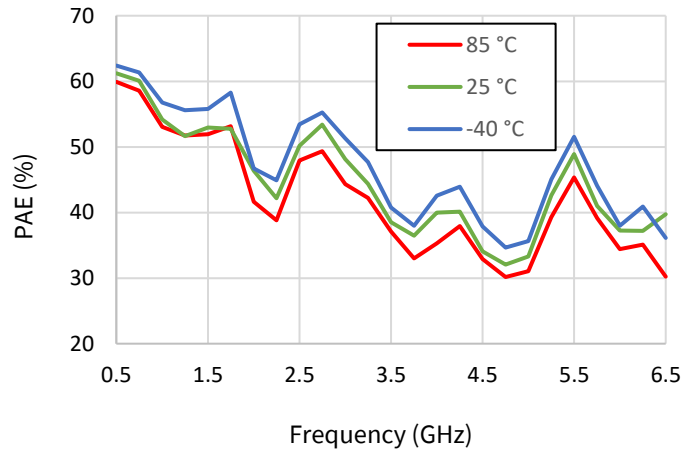
Parameter	Units	Frequency	Min	Typical	Max	Conditions
Frequency	GHz		0.5		6	
Output Power	dBm	0.5		40		Pin = 28 dBm
		3		40		
		6		40		
Power-added Efficiency	%	0.5		60		Pin = 28 dBm
		3		44		
		6		36		
LSG	dB	0.5		12		Pin = 28 dBm
		3		12		
		6		12		
Small-Signal Gain (S21)	dB	0.5		21		Pin = -20 dBm
		3		19		
		6		19		
Input Return Loss	dB			-11		Pin = -20 dBm
Output Return Loss	dB			-8		Pin = -20 dBm

Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=0.220\text{ A}$ , CW,  $P_{in} = 28\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$ , Frequency: 3GHz

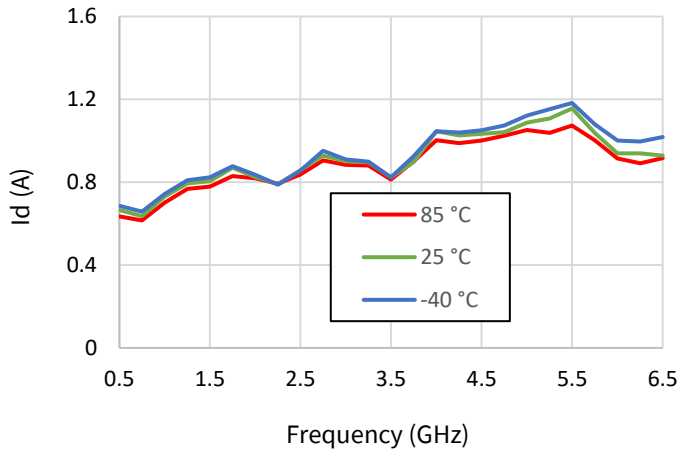
**Figure 3: Pout v. Frequency v. Temperature**



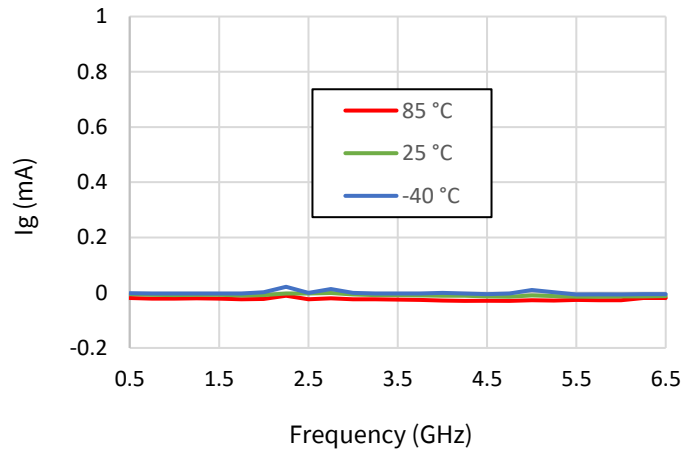
**Figure 4: PAE v. Frequency v. Temperature**



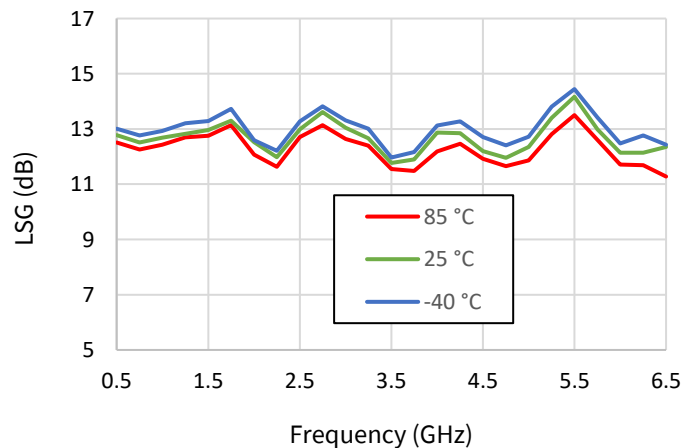
**Figure 5: Id v. Frequency v. Temperature**



**Figure 6: Ig v. Frequency v. Temperature**

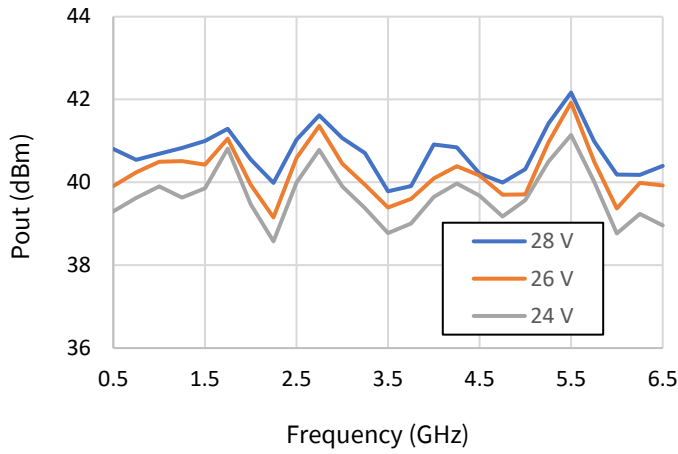


**Figure 7: LSG v. Frequency v. Temperature**

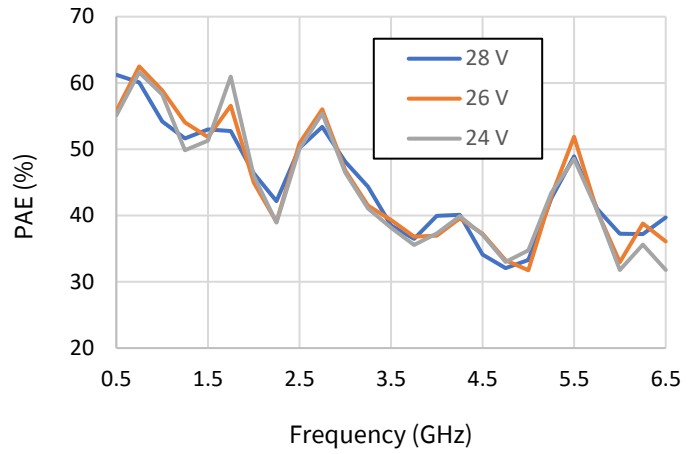


Test conditions unless otherwise noted: Vd=28 V, Idq=0.220A, CW, Pin = 28 dBm, T<sub>base</sub>=25°C, Frequency: 3GHz

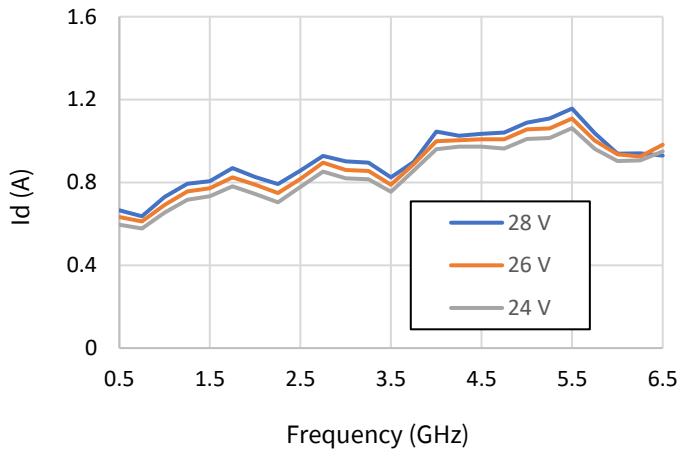
**Figure 8: Pout v. Frequency v. Vd**



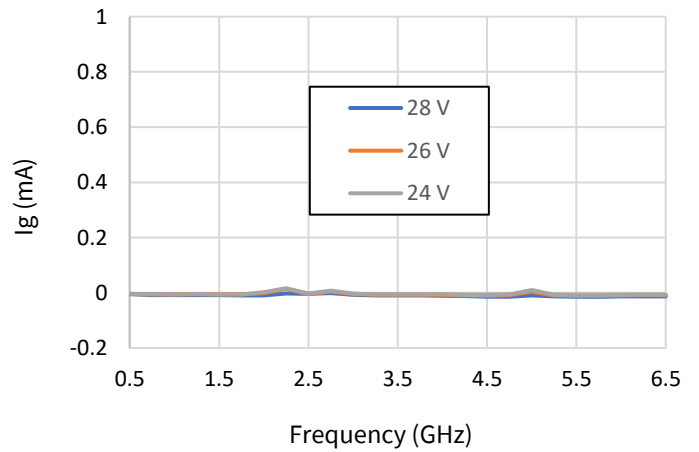
**Figure 9: PAE v. Frequency v. Vd**



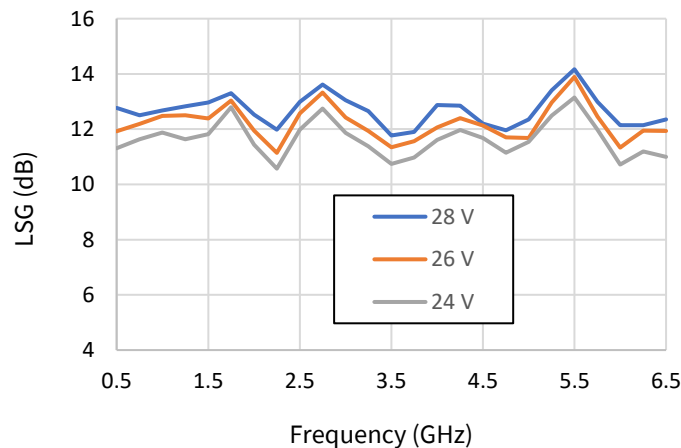
**Figure 10: Id v. Frequency v. Vd**



**Figure 11: Ig v. Frequency v. Vd**

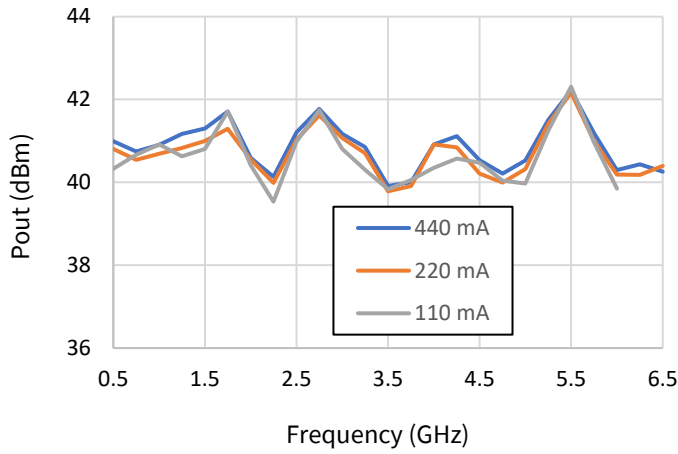


**Figure 12: LSG v. Frequency v. Vd**

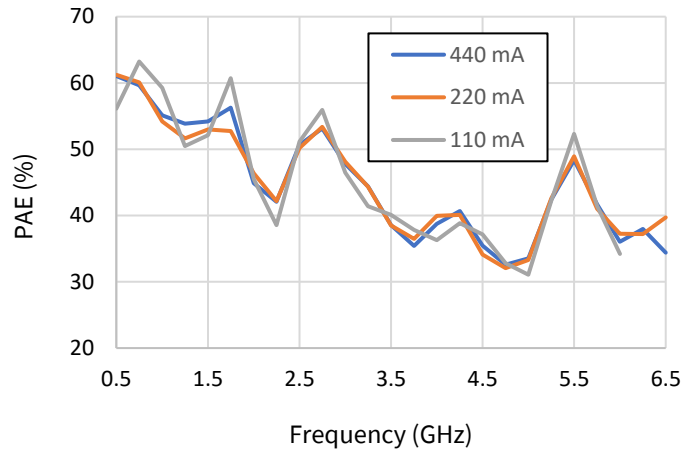


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=0.220\text{ A}$ , CW,  $P_{in} = 28\text{ dBm}$ ,  $T_{base}=25^\circ\text{C}$ , Frequency: 3GHz

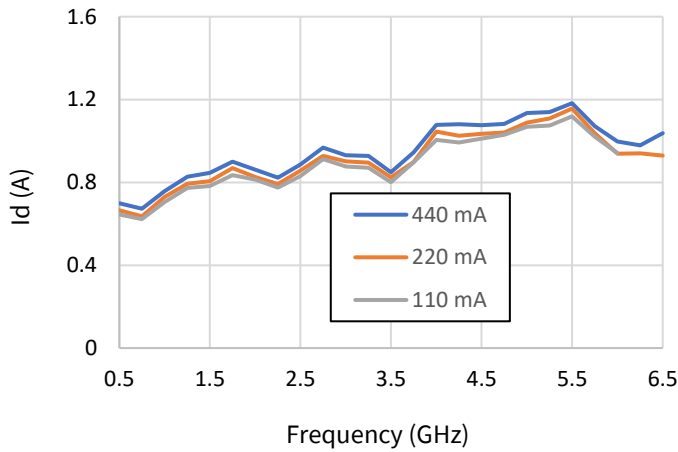
**Figure 13: Pout v. Frequency v. Idq**



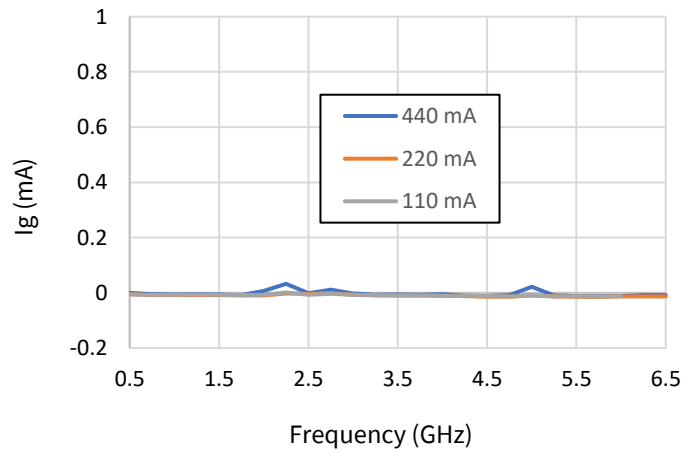
**Figure 14: PAE v. Frequency v. Idq**



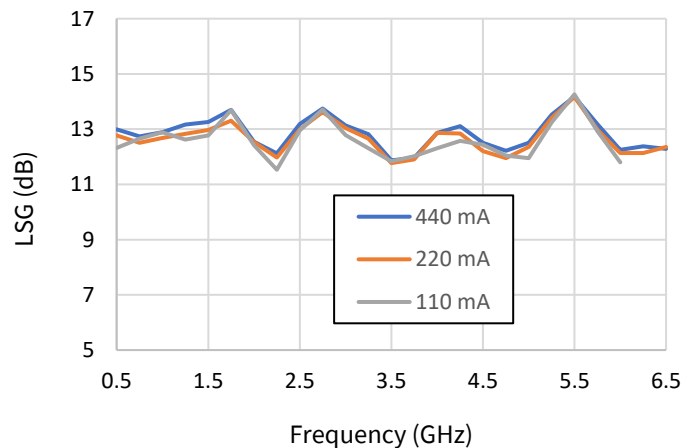
**Figure 15: Id v. Frequency v. Idq**



**Figure 16: Ig v. Frequency v. Idq**

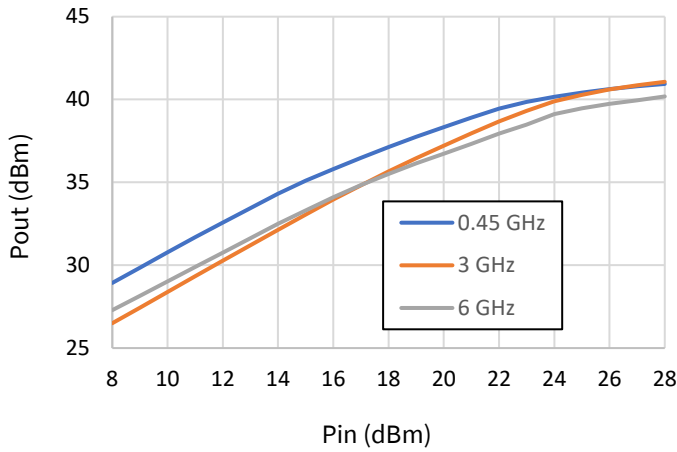


**Figure 17: LSG v. Frequency v. Idq**

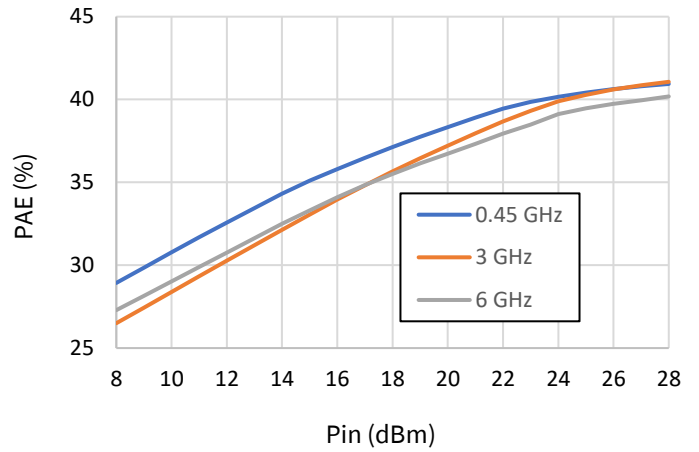


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=0.220\text{ A}$ , CW,  $P_{in} = 28\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$ , Frequency: 3GHz

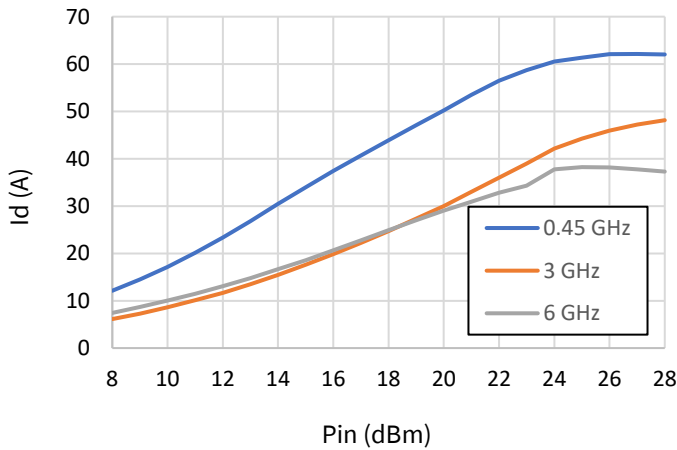
**Figure 18: Pout v. Pin v. Frequency**



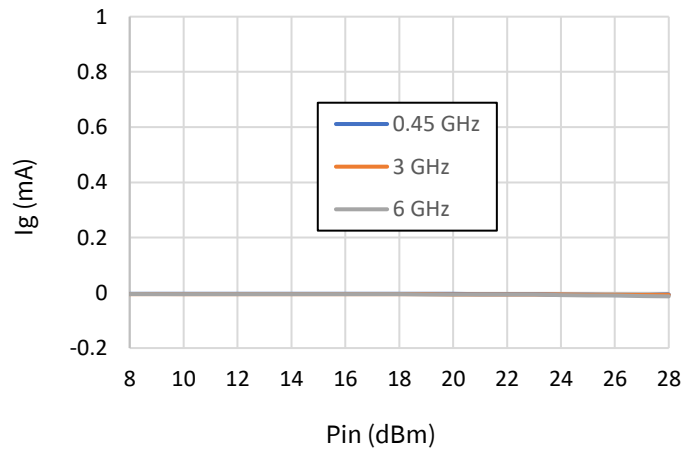
**Figure 19: PAE v. Pin v. Frequency**



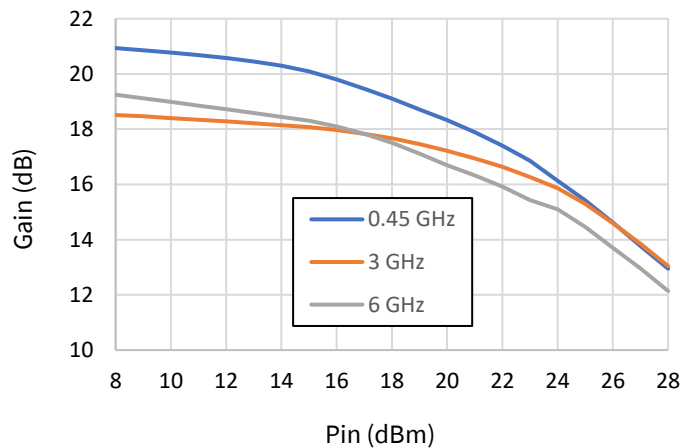
**Figure 20: Id v. Pin v. Frequency**



**Figure 21: Ig v. Pin v. Frequency**

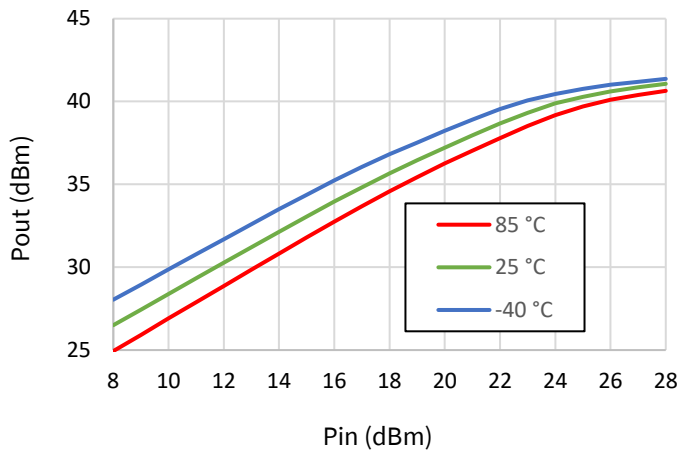


**Figure 22: Gain v. Pin v. Frequency**

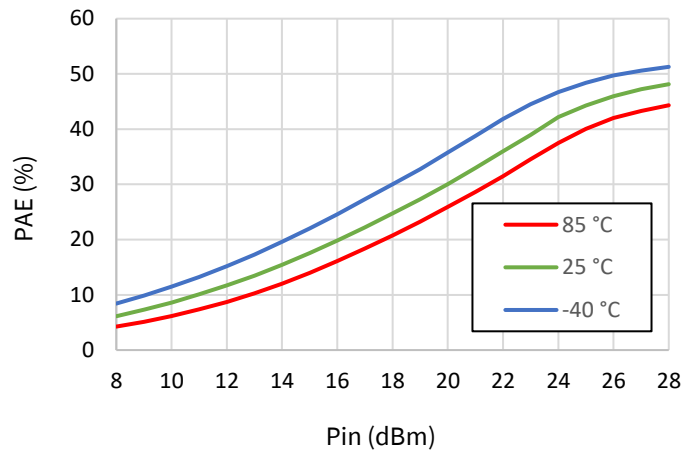


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=0.220\text{ A}$ , CW,  $P_{in} = 28\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$ , Frequency: 3GHz

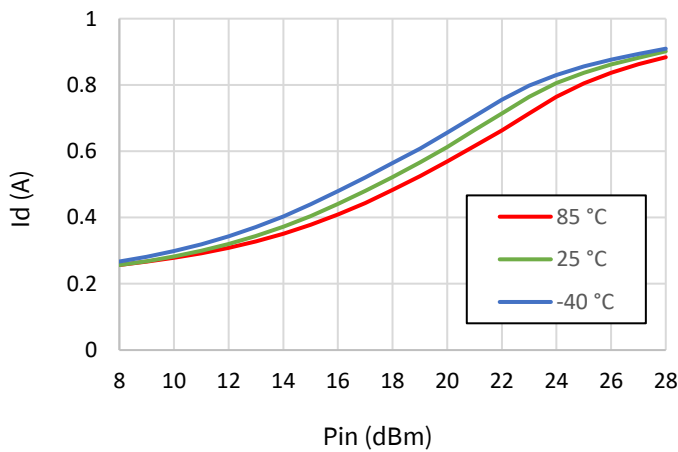
**Figure 23: Pout v. Pin v. Temperature**



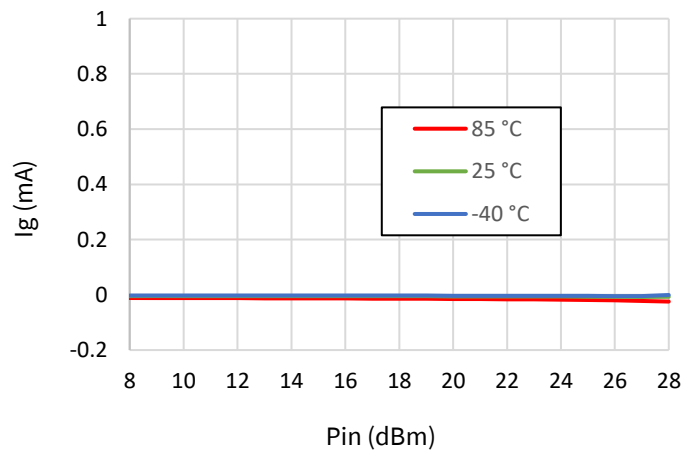
**Figure 24: PAE v. Pin v. Temperature**



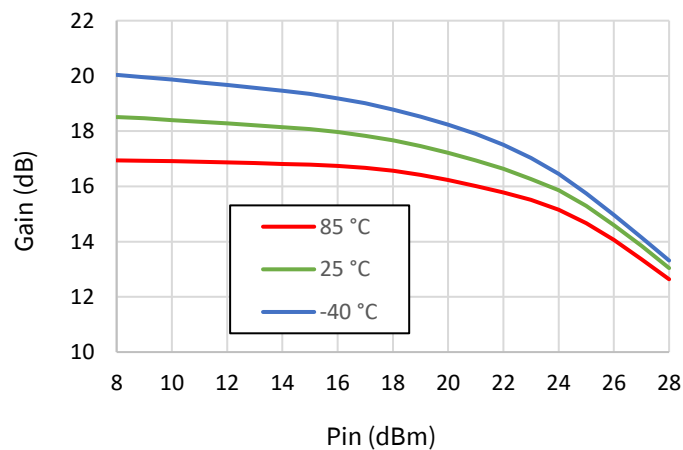
**Figure 25: Id v. Pin v. Temperature**



**Figure 26: Ig v. Pin v. Temperature**

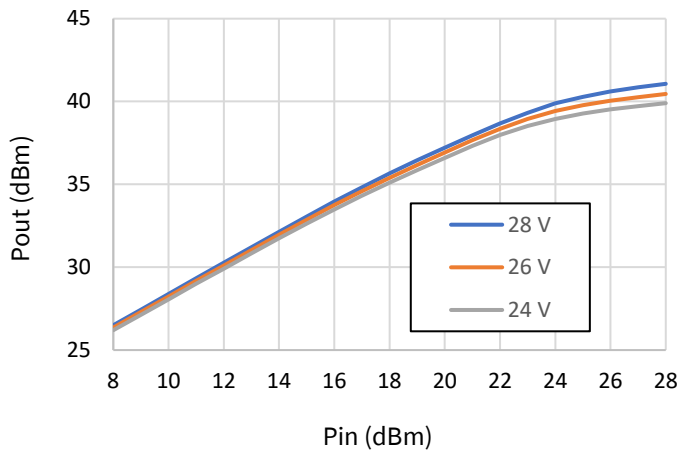


**Figure 27: Gain v. Pin v. Temperature**

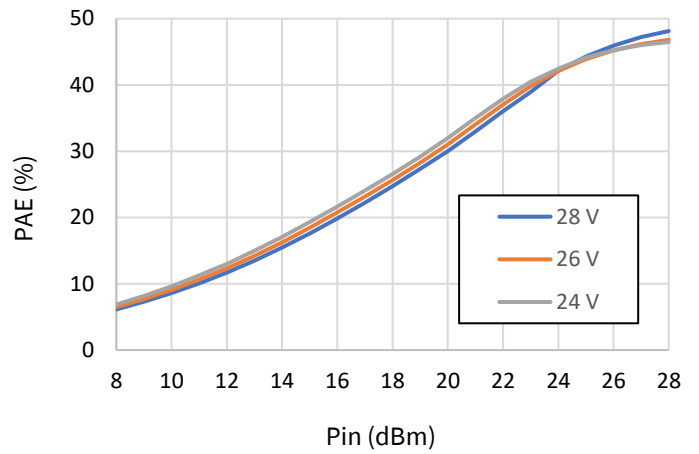


Test conditions unless otherwise noted: Vd=28 V, Idq=0.220A, CW, Pin = 28 dBm, T<sub>base</sub>=25 °C, Frequency: 3GHz

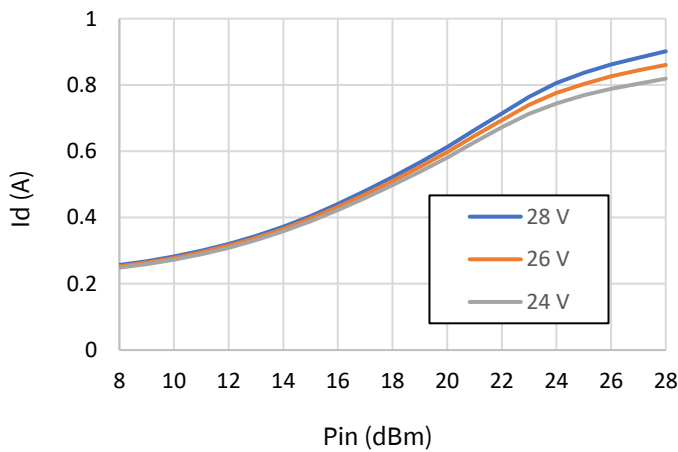
**Figure 28: Pout v. Pin v. Vd**



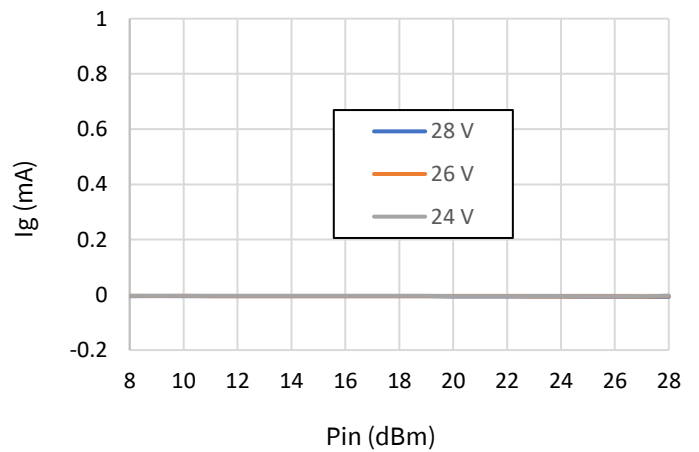
**Figure 29: PAE v. Pin v. Vd**



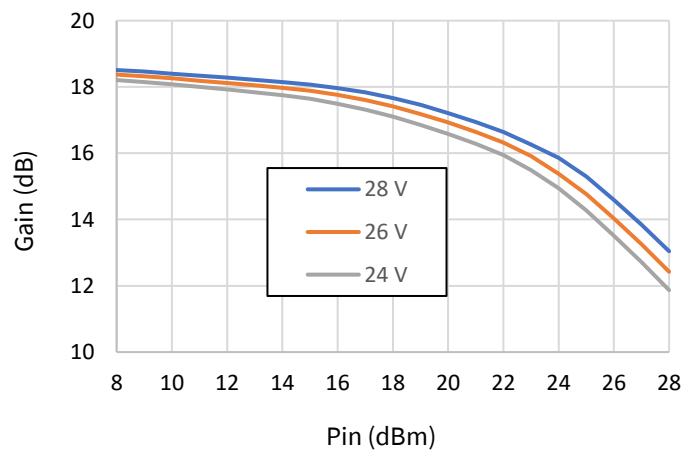
**Figure 30: Id v. Pin v. Vd**



**Figure 31: Ig v. Pin v. Vd**



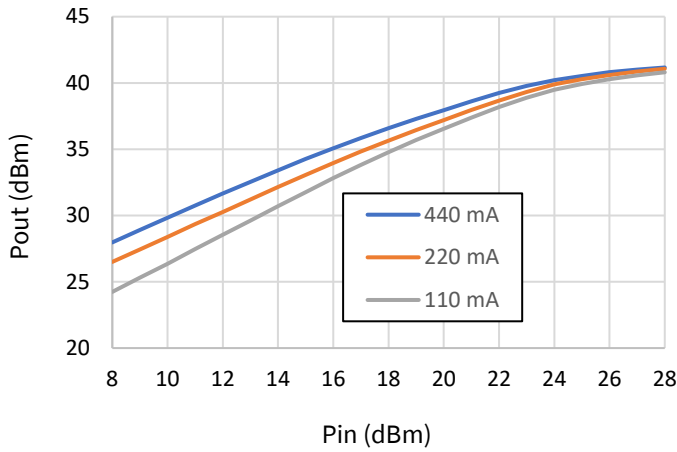
**Figure 32: Gain v. Pin v. Vd**



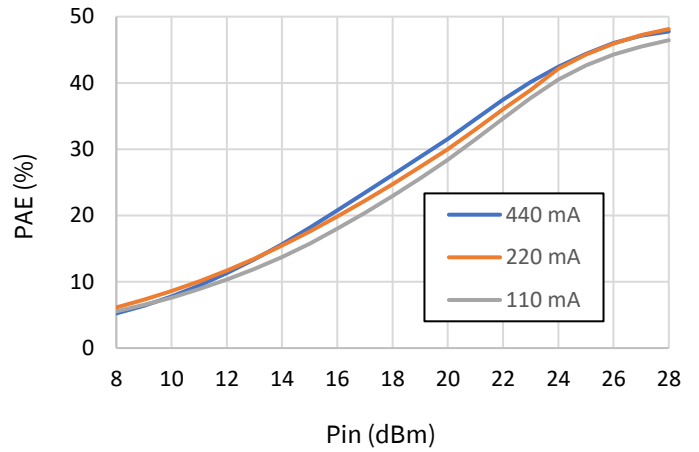


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=0.220\text{ A}$ , CW,  $P_{in} = 28\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$ , Frequency: 3GHz

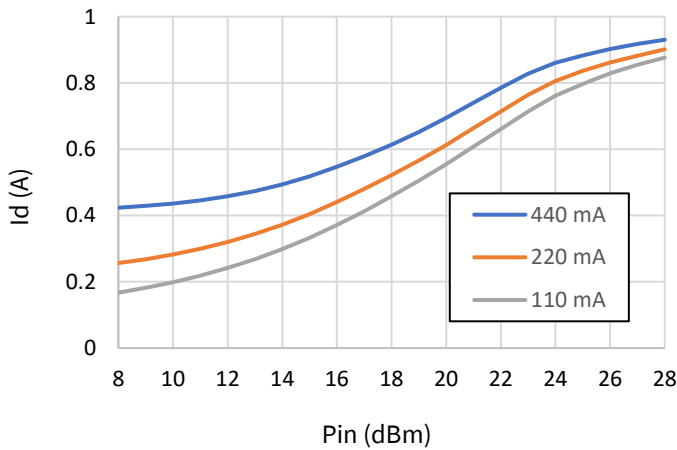
**Figure 33: Pout v. Pin v. Idq**



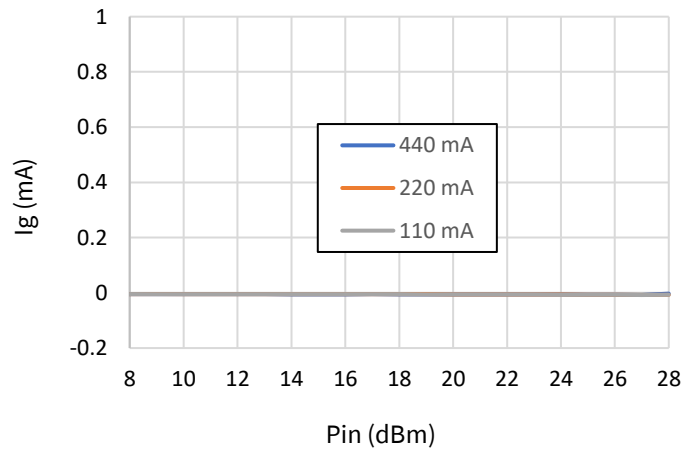
**Figure 34: PAE v. Pin v. Idq**



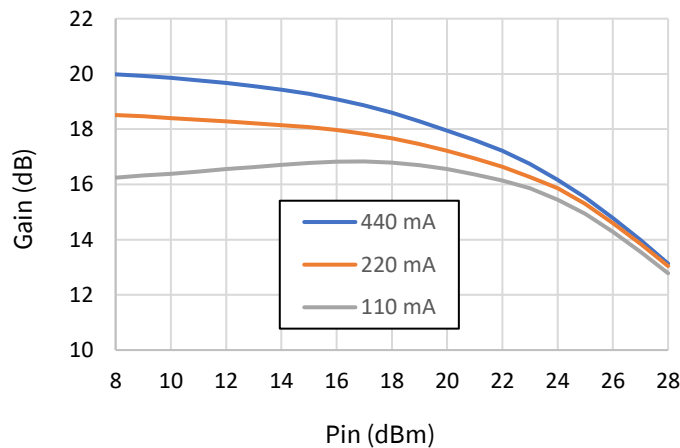
**Figure 35: Id v. Pin v. Idq**



**Figure 36: Ig v. Pin v. Idq**

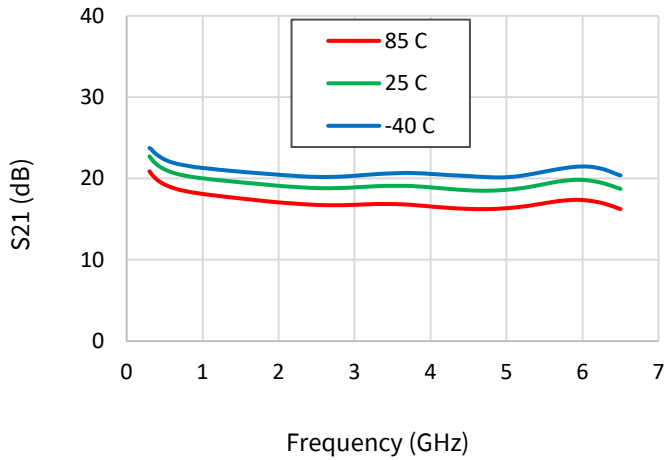


**Figure 37: Gain v. Pin v. Idq**

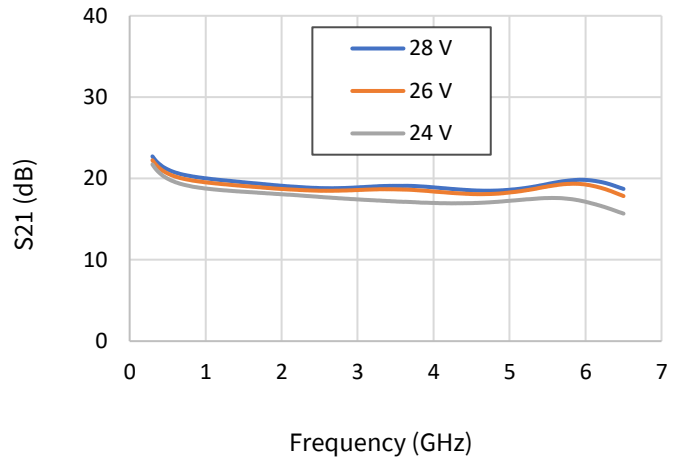


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=0.220\text{ A}$ , CW,  $P_{in} = -10\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$

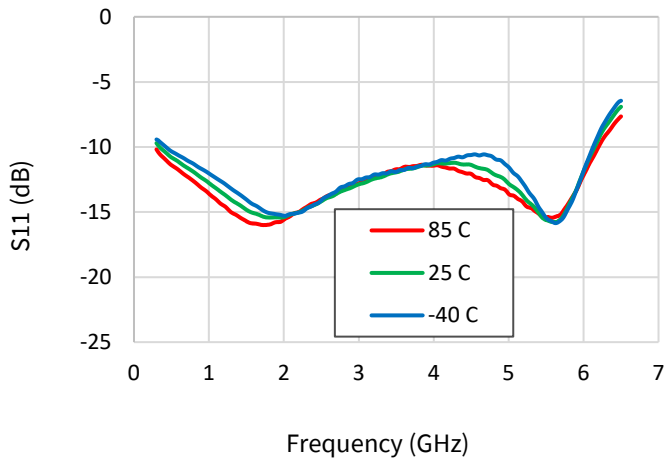
**Figure 38: S21 v. Frequency v. Temperature**



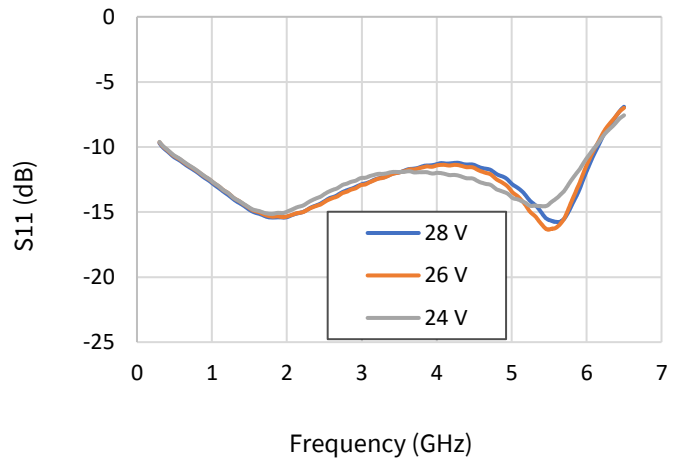
**Figure 39: S21 v. Frequency v. Vd**



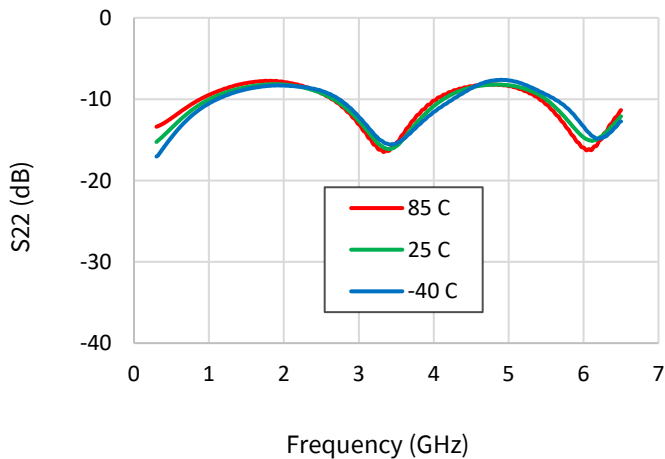
**Figure 40: S11 v. Frequency v. Temperature**



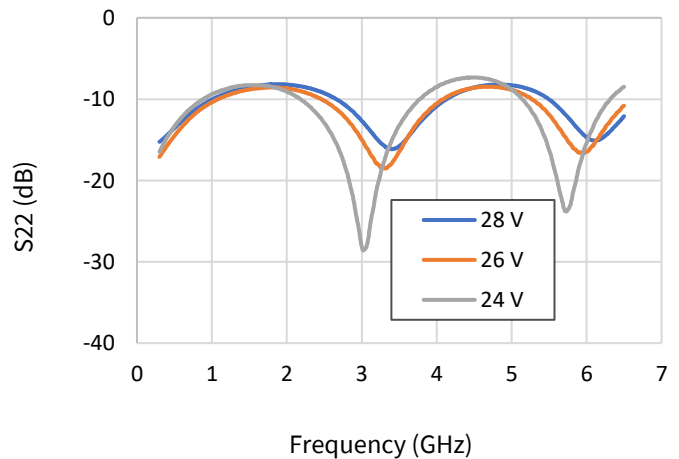
**Figure 41: S11 v. Frequency v. Vd**



**Figure 42: S22 v. Frequency v. Temperature**

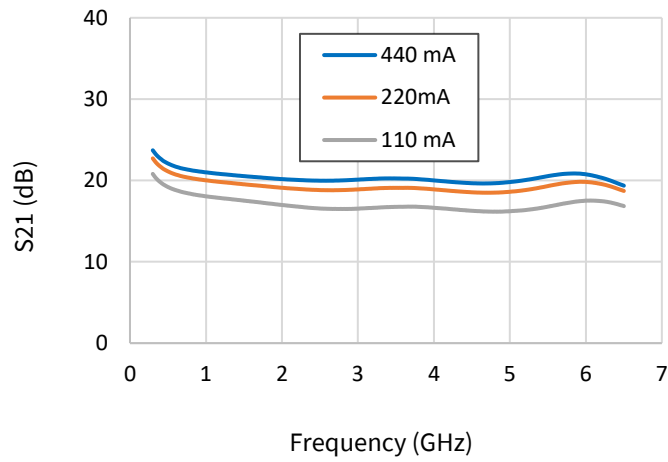


**Figure 43: S22 v. Frequency v. Vd**

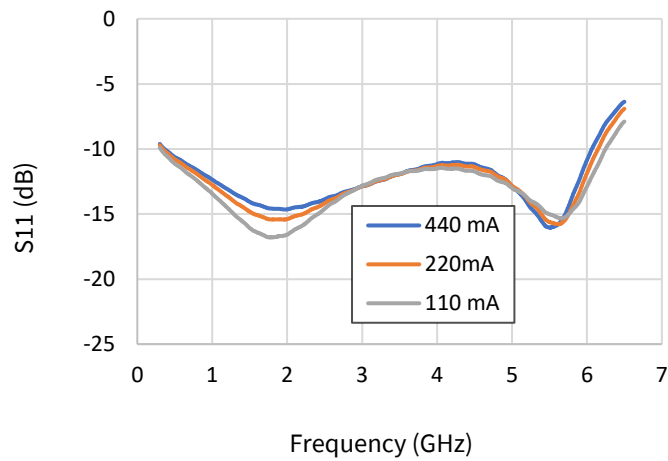


Test conditions unless otherwise noted:  $V_d=28\text{ V}$ ,  $I_{dq}=0.220\text{ A}$ , CW,  $P_{in} = -10\text{ dBm}$ ,  $T_{base}=25\text{ }^\circ\text{C}$

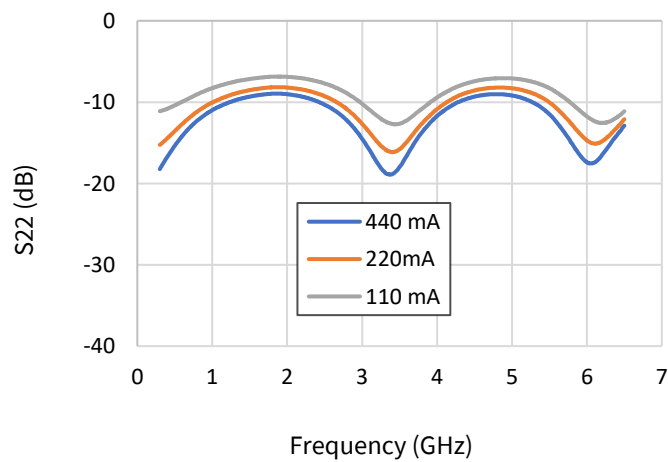
**Figure 44: S21 v. Frequency v. Idq**



**Figure 45: S11 v. Frequency v. Idq**



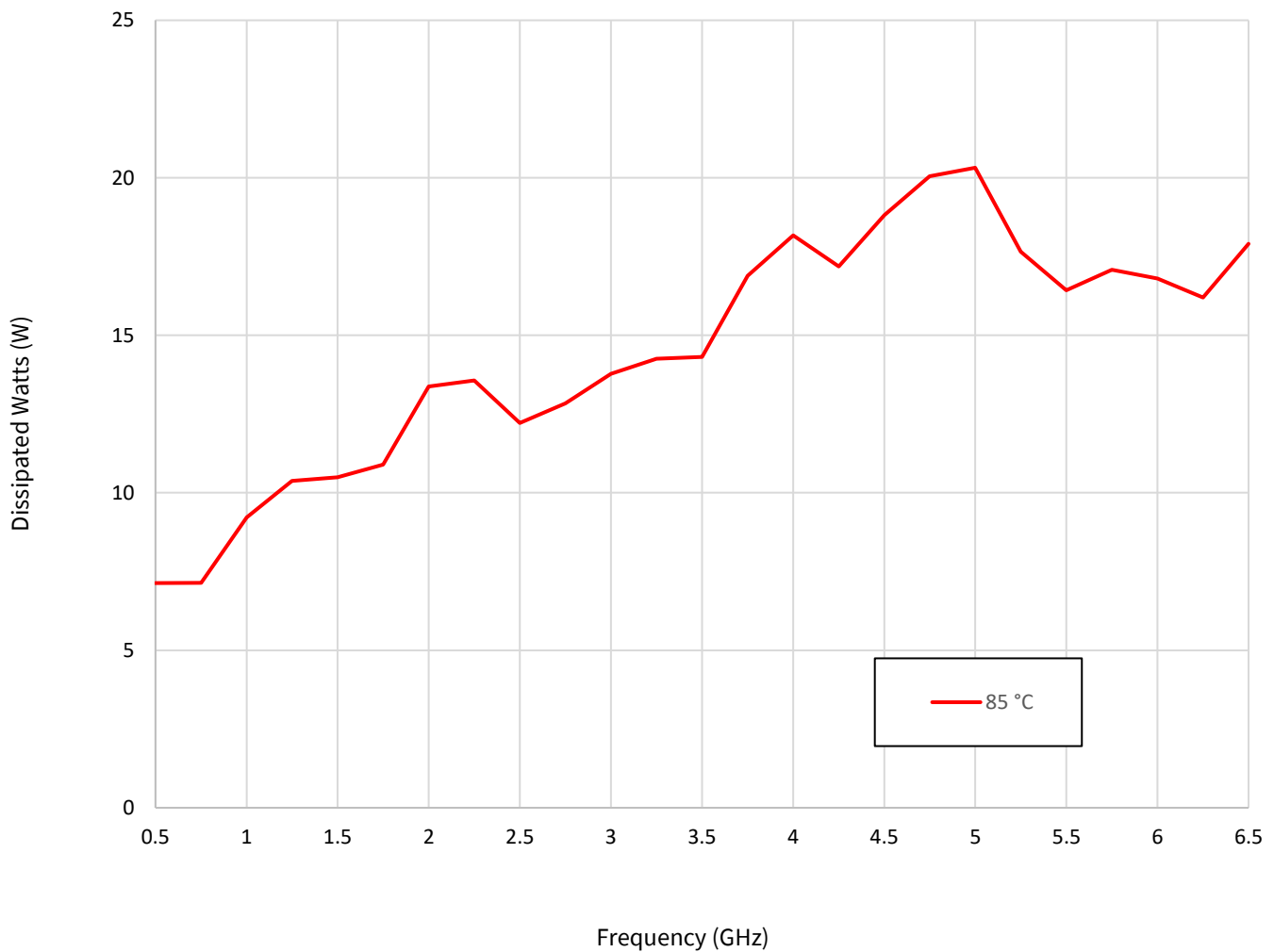
**Figure 46: S22 v. Frequency v. Idq**



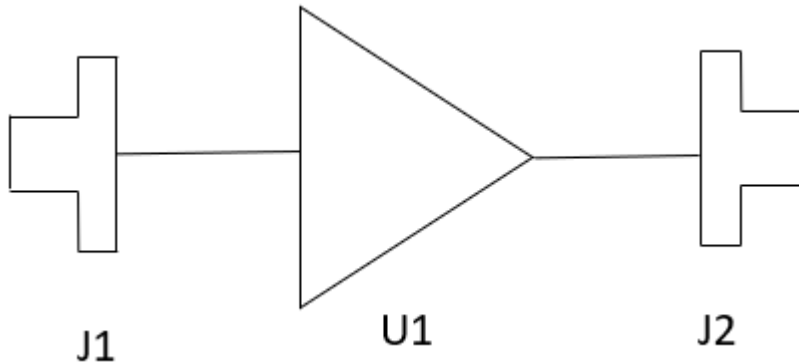
### Thermal Characteristics

Parameter	Symbol	Value	Operating Conditions
Operating Junction Temperature	$T_J$	131°C	Freq = 3.0 GHz, $V_d = 28$ V, $I_{dq} = 220$ mA, $I_{drive} = 0.88$ A, $P_{in} = 28$ dBm, $P_{out} = 40.6$ dBm, $P_{diss} = 13.8$ W, $T_{case} =$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	3.3°C/W	

### Power Dissipation v. Frequency ( $T_{case} = 85^\circ\text{C}$ )

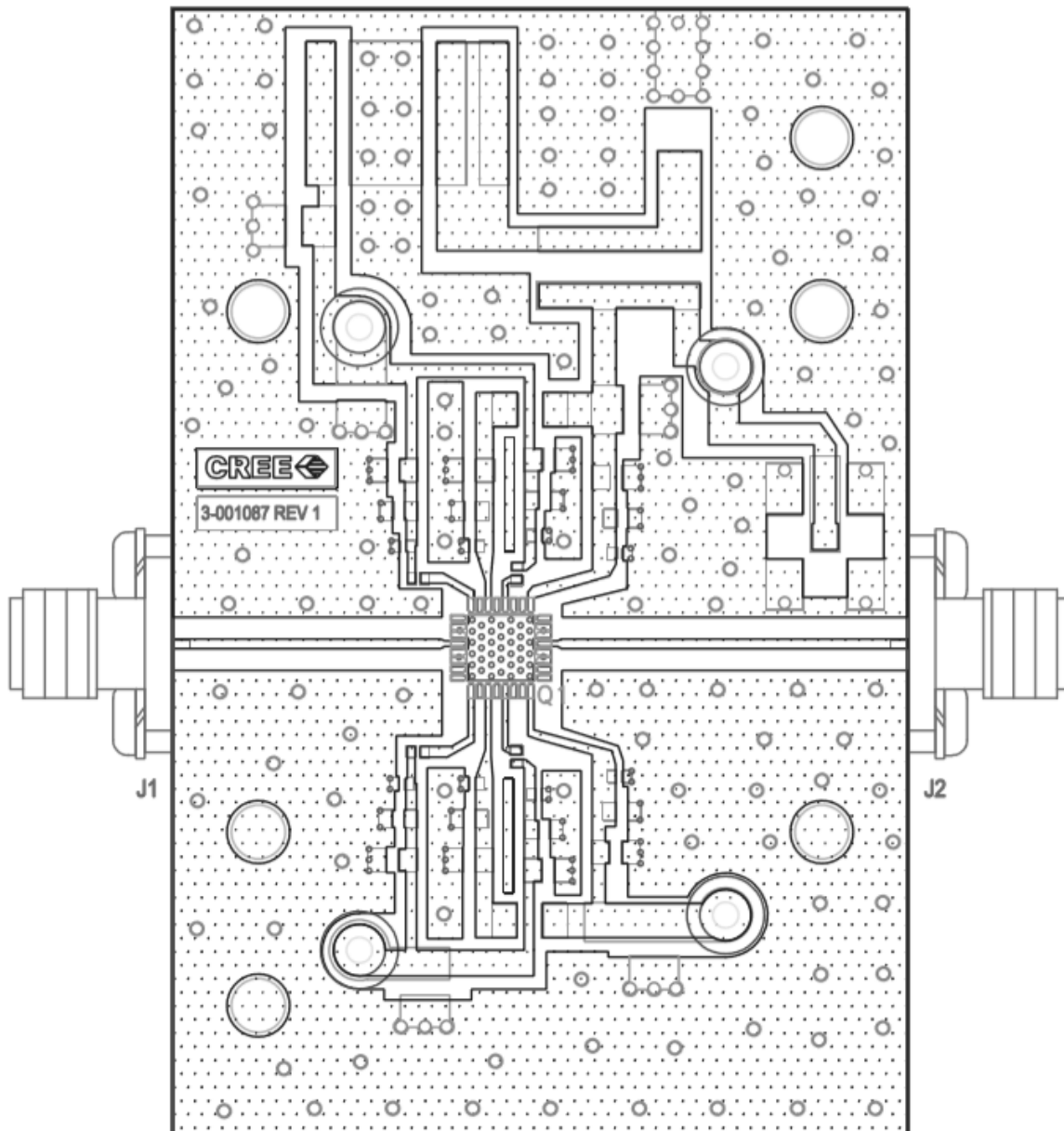


**CMPA0560008S-AMP1 Evaluation Board Schematic Drawing**



**CMPA0560008S-AMP1 Evaluation Board Bill of Materials**

Reference Designator	Description	Qty
J1, J2	CONN, SMA, PANEL MOUNT JACK, FLANGE, 4-HOLE, BLUNT POST, 20MIL	2
U1	CMPA0560008S	1
-	PCB, TEST FIXTURE, RF35, 0.010", 5X5 2-STAGE, QFN	1
-	2-56 SOC HD SCREW 3/16 SS	4
-	#2 SPLIT LOCKWASHER SS	4

**CMPA0560008S-AMP1 Evaluation Board Assembly Drawing****Bias On Sequence**

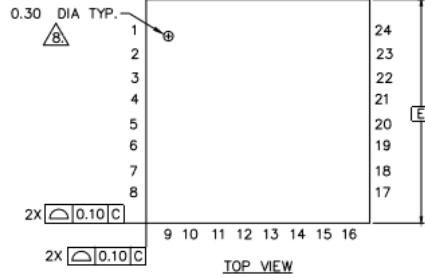
1. Ensure RF is turned-off
2. Apply pinch-off voltage of -5 V to the gate ( $V_g$ )
3. Apply nominal drain voltage ( $V_d$ )
4. Adjust  $V_g$  to obtain desired quiescent drain current ( $I_{dq}$ )
5. Apply RF

**Bias Off Sequence**

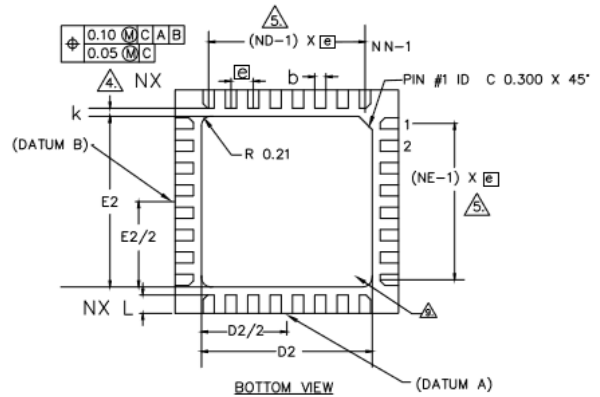
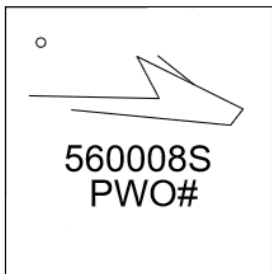
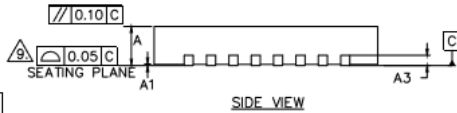
1. Turn RF off
2. Apply pinch-off to the gate ( $V_g = -5V$ )
3. Turn off drain voltage ( $V_d$ )
4. Turn off gate voltage ( $V_g$ )

**Product Dimensions**

SYMBOL	MIN.	NOM.	MAX.	NOTE
A	0.80	0.90	1.00	
A1	0.00	0.03	0.06	
A3	0.203 REF.			
⊖	0		12	2
K	0.17 MIN.			
D	5.0 BSC			
E	5.0 BSC			



0.50mm LEAD PITCH				NOTE
SYMBOL	MIN.	NOM.	MAX.	
⊖	0.50 BSC.			
N	32			3
ND	8			3
NE	8			3
L	0.35	0.41	0.46	
b	0.21	0.25	0.29	
D2	3.76	3.82	3.88	
E2	3.76	3.82	3.88	



**NOTES :**

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5M. – 1994.
2. ALL DIMENSIONS ARE IN MILLIMETERS, θ IS IN DEGREES.
3. N IS THE TOTAL NUMBER OF TERMINALS.
4. DIMENSION b APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM TERMINAL TIP.
5. ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.
6. MAX. PACKAGE WARPAGE IS 0.05 mm.
7. MAXIMUM ALLOWABLE BURRS IS 0.076 mm IN ALL DIRECTIONS.
8. PIN #1 ID ON TOP WILL BE LASER MARKED.
9. BILATERAL COPLANARITY ZONE APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
10. THIS DRAWING CONFORMS TO JEDEC REGISTERED OUTLINE MO-220
11. ALL PLATED SURFACES ARE 100% TIN MATTE 0.010 mm +/- 0.005 mm.


PIN	DESC.	PIN	DESC.
1	NC	17	NC
2	NC	18	NC
3	RFGND	19	NC
4	RFIN / Vg	20	RFGND
5	RFGND	21	RFOUT / Vd
6	NC	22	RFGND
7	NC	23	NC
8	NC	24	NC
9	NC	25	NC
10	NC	26	NC
11	NC	27	NC
12	NC	28	NC
13	NC	29	NC
14	NC	30	NC
15	NC	31	NC
16	NC	32	NC

## Electrostatic Discharge (ESD) Classification

Parameter	Symbol	Class	Classification Level	Test Methodology
Human body Model	HBM	TBD	ANSI/ESDA/JEDEC JS-001 Table 3	JEDEC JESD22 A114-D
Charge Device Model	CDM	TBD	ANSI/ESDA/JEDEC JS-002 Table 3	JEDEC JESD22 C101-C



## Product Ordering Information

Part Number	Description	MOQ Increment	Image
CMPA0560008S	0.5 – 6 GHz, 10W GaN MMIC		
CMPA0560008S-AMP1	Evaluation Board w/ PA	1 Each	

For more information, please contact:

### Mailing Address

4600 Silicon Drive  
 Durham, North Carolina, USA 27703  
[www.wolfspeed.com/RF](http://www.wolfspeed.com/RF)

### Sales Contact

[RFSales@wolfspeed.com](mailto:RFSales@wolfspeed.com)

### RF Product Marketing Contact

[RFMarketing@wolfspeed.com](mailto:RFMarketing@wolfspeed.com)

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